

### STL128DN

### High voltage fast-switching NPN power transistor

#### **Features**

- High voltage capability
- Low spread of dynamic parameters
- Very high switching speed
- Large RBSOA
- Integrated antiparallel collector-emitter diode

### **Applications**

- Electronic ballast for fluorescent lighting
- Flyback and forward single transistor low power converters

### **Description**

The device is manufactured using high voltage multi epitaxial planar technology for high switching speeds and medium voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA. The device is designed for use in lighting applications and low cost switch-mode power supplies.

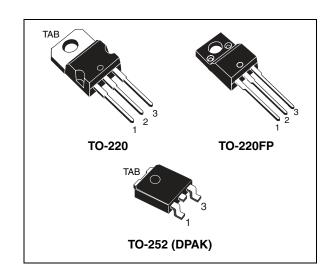


Figure 1. Internal schematic diagram

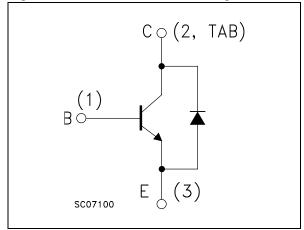


Table 1. Device summary

Order codes	Marking	Packages	Packaging
STL128DN	L128DN	TO-220	Tube
STL128DNFP	L128DNFP	TO-220FP	Tube
STLD128DNT4	LD128DN	DPAK	Tape and reel

Content STL128DN

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STL128DN Electrical ratings

# 1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>CES</sub>	Collector-emitter voltage (V <sub>BE</sub> = 0)	700	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	400	V
V <sub>EBO</sub>	Base-emitter voltage ( $I_C = 0$ , $I_B = 2$ A, $t_P < 10 \mu s$ )	$V_{(BR)EBO}$	V
I <sub>C</sub>	Collector current	4	Α
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5 ms)	8	Α
I <sub>B</sub>	Base current	2	Α
I <sub>BM</sub>	Base peak current (t <sub>P</sub> < 5 ms)	4	Α
	Total dissipation at T <sub>c</sub> = 25 °C for TO-220	60	W
P <sub>TOT</sub>	Total dissipation at $T_c$ = 25 °C for TO-220FP	28	W
	Total dissipation at T <sub>c</sub> = 25 °C for DPAK	20	W
T <sub>stg</sub>	Storage temperature	-65 to 150	°C
$T_J$	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	TO-220	TO-220FP	DPAK	Unit
R <sub>thJC</sub>	Thermal resistance junction-case max	2.08	4.46	6.25	°C/W

Electrical characteristics STL128DN

### 2 Electrical characteristics

 $T_{case}$  = 25 °C unless otherwise specified

Table 4. Electrical characteristics

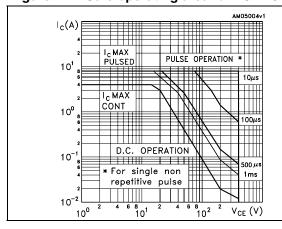
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CES</sub>	Collector cut-off current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = 700 V V <sub>CE</sub> = 700 V T <sub>c</sub> = 125 °C			100 500	μ <b>Α</b> μ <b>Α</b>
I <sub>CEO</sub>	Collector cut-off current (I <sub>B</sub> = 0)	V <sub>CE</sub> = 400 V			250	μΑ
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = 10 mA	9		18	V
V <sub>CEO(sus)</sub> <sup>(1)</sup>	Collector-emitter sustaining voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 10 mA	400			V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	$I_C = 1 \text{ A}$ $I_B = 0.2 \text{ A}$ $I_C = 2 \text{ A}$ $I_B = 0.4 \text{ A}$			0.5 1	V V
V <sub>BE(sat)</sub> <sup>(1)</sup>	Base-emitter saturation voltage	$I_C = 1 \text{ A}$ $I_B = 0.2 \text{ A}$ $I_C = 2 \text{ A}$ $I_B = 0.4 \text{ A}$			1.2 1.3	V V
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$I_C = 10 \text{ mA}$ $V_{CE} = 5 \text{ V}$ $I_C = 2 \text{ A}$ $V_{CE} = 5 \text{ V}$			24	
$V_{F}$	Diode forward voltage	I <sub>F</sub> = 1 A			2.5	V
t <sub>s</sub>	Resistive load Storage time Fall time	$I_C = 1 \text{ A}$ $I_{B1} = -I_{B2} = 0.2$ $V_{CC} = 125 \text{ V}$ $t_p = 20 \text{ µs}$			4.5 0.4	μs μs

<sup>1.</sup> Pulse test: pulse duration  $\leq 300~\mu s,$  duty cycle  $\leq~2~\%.$ 

#### 2.1 Electrical characteristics (curves)

Figure 2. Safe operating area for TO-220

Figure 3. Safe operating area for TO-220FP



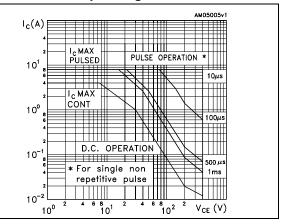
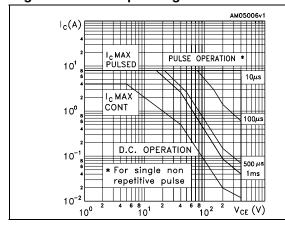


Figure 4. Safe operating area for DPAK

Figure 5. Derating curve



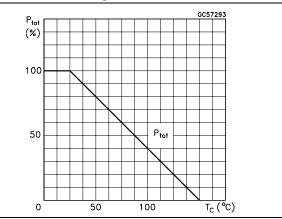
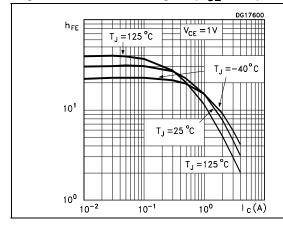
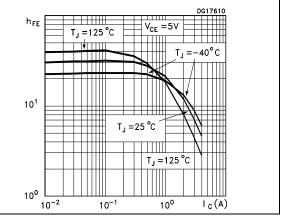


Figure 6. DC current gain  $(V_{CE} = 1 V)$ 

Figure 7. DC current gain  $(V_{CE} = 5 V)$ 





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Figure 8. Collector-emitter saturation voltage Figure 9. Base-emitter saturation voltage

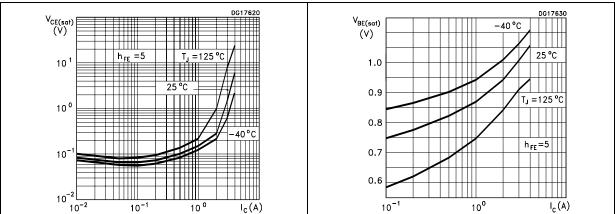


Figure 10. Freewheel diode forward voltage

Figure 11. Resistive load switching time

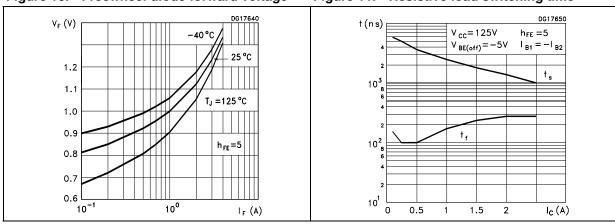
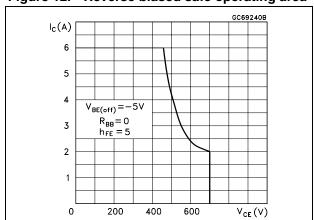


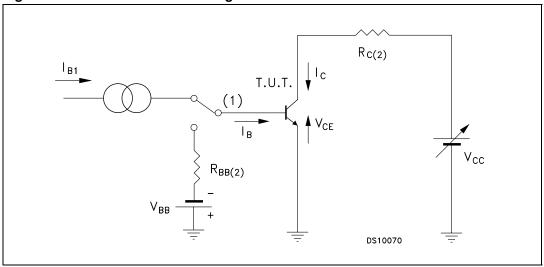
Figure 12. Reverse biased safe operating area



STL128DN Test circuit

## 3 Test circuit

Figure 13. Resistive load switching test circuit



- 1. Fast electronic switch
- 2. Non-inductive resistor

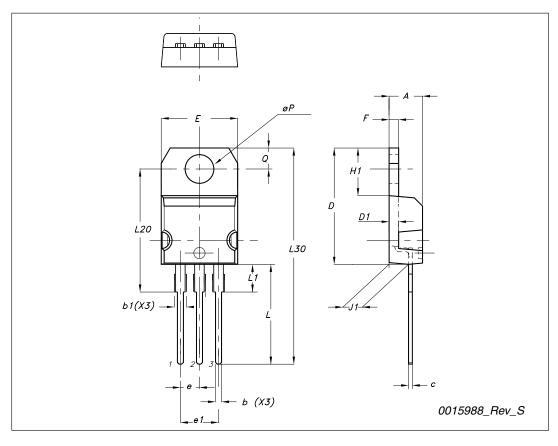
## 4 Package mechanical data

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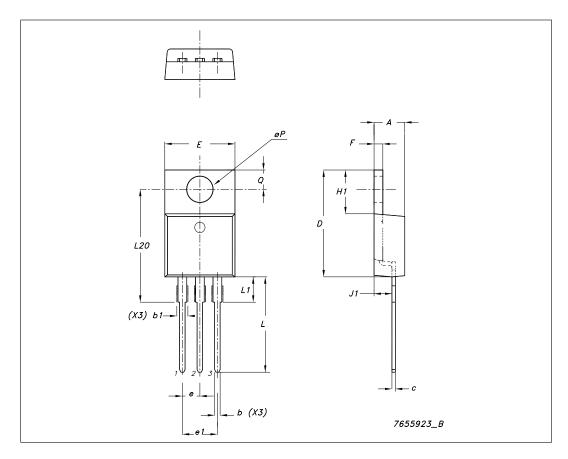
#### TO-220 type A mechanical data

Dim		mm	
Dim	Min	Тур	Max
Α	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
С	0.48		0.70
D	15.25		15.75
D1		1.27	
E	10		10.40
е	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
ØP	3.75		3.85
Q	2.65		2.95



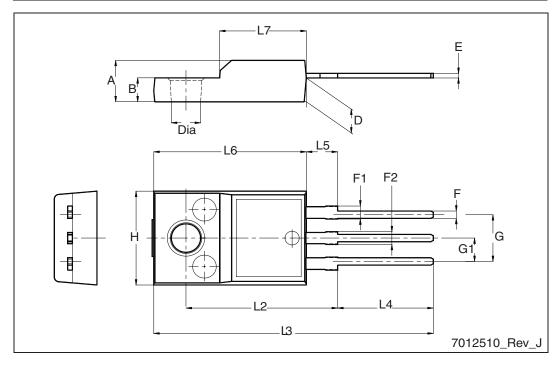
#### TO-220 type E mechanical data

Dim		mm	
Dim	Min	Тур	Max
Α	4.47		4.67
b	0.70		0.91
b1	1.17		1.37
С	0.31		0.53
D	14.60		15.70
E	9.96		10.36
е		2.54	
e1	4.98	5.08	5.18
F	1.17		1.37
H1	6.10		6.80
J1	2.52		2.82
L	12.70		13.80
L1	3.20		3.96
L20	15.21		16.77
øΡ	3.73		3.94
Q	2.59		2.89



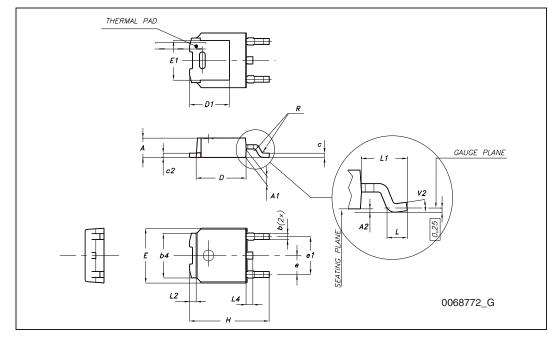
#### TO-220FP mechanical data

Dim.		mm	
Dilli.	Min.	Тур.	Max.
Α	4.4		4.6
В	2.5		2.7
D	2.5		2.75
E	0.45		0.7
F	0.75		1
F1	1.15		1.70
F2	1.15		1.5
G	4.95		5.2
G1	2.4		2.7
Н	10		10.4
L2		16	
L3	28.6		30.6
L4	9.8		10.6
L5	2.9		3.6
L6	15.9		16.4
L7	9		9.3
Dia	3		3.2



TO-252	(DPAK)	) mechanical	data
10-232		/ 111 <del>C</del> CHarica	uata

DIM.		mm.	
Dilvi.	min.	typ	max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
С	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
е		2.28	
e1	4.40		4.60
Н	9.35		10.10
L	1		
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0 °		8 °



STL128DN Revision history

# 5 Revision history

Table 5. Document revision history

Date	Revision	Changes
04-Oct-2007	1	First release
14-Feb-2008	2	Updated TO-220, type E, mechanical data
01-Oct-2009	3	Updated: collector and base current values <i>Table 2 on page 3</i> , V <sub>CE(sat)</sub> maximum values <i>Table 4 on page 4</i> .

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